NSN 5961-01-275-8265

Transistor - Page 1 of 1

Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-275-8265 **Inclosure Material:** Metal **Overall Length:** 1.500 inches **Overall Height:** 0.450 inches **Overall Width:** 1.000 inches **Mounting Facility Quantity: Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 475.0 breakdown voltage, drain-to-source, with all other terminals short-circuited to source and 3.6 gate to source threshold voltage and 6.0 gate to source threshold voltage **Current Rating Per Characteristic:** 2.00 milliamperes zero-gate-voltage drain current **Power Rating Per Characteristic:** 125.0 watts total power dissipation **Terminal Type And Quantity:** 2 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No